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Bib Data Sheet

CONFIRMATION NO. 4501

SERIAL NUMBER 10/807,235	FILING DATE 03/24/2004  RULE	CLASS 438	GROUP ART UNIT 2826	ATTORNEY DOCKET NO. 119232
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\*\* CONTINUING DATA \*\*\*\*\*

None. EP

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN 2003-172182 06/17/2003

verified. EP

IF REQUIRED, FOREIGN FILING LICENSE GRANTED \*\* SMALL ENTITY \*\*

\*\* 06/02/2004

Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	STATE OR COUNTRY JAPAN	SHEETS DRAWING 2	TOTAL CLAIMS 19	INDEPENDENT CLAIMS 1
Verified and Acknowledged	Examiner's Signature <i>[Signature]</i> Initials <i>EP</i>				

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## TITLE

Method for fabricating a metallic oxide of high dielectric constant, metallic oxide of high dielectric constant, gate insulating film and semiconductor element

☐ All Fees

☐ 1.16 Fees ( Filing )

FILING FEE  RECEIVED 385	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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